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Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

Details

Product Status	Active
Core Processor	ARM® Cortex®-M3
Core Size	32-Bit Single-Core
Speed	72MHz
Connectivity	CANbus, I ² C, IrDA, LINbus, SPI, UART/USART, USB
Peripherals	DMA, Motor Control PWM, PDR, POR, PVD, PWM, Temp Sensor, WDT
Number of I/O	51
Program Memory Size	64KB (64K x 8)
Program Memory Type	FLASH
EEPROM Size	•
RAM Size	20K x 8
Voltage - Supply (Vcc/Vdd)	2V ~ 3.6V
Data Converters	A/D 16x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	64-LQFP
Supplier Device Package	64-LQFP (10x10)
Purchase URL	https://www.e-xfl.com/product-detail/stmicroelectronics/stm32f103r8t7

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

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SysTick timer

This timer is dedicated for OS, but could also be used as a standard downcounter. It features:

- A 24-bit downcounter
- Autoreload capability
- Maskable system interrupt generation when the counter reaches 0
- Programmable clock source

2.3.16 I²C bus

Up to two I²C bus interfaces can operate in multimaster and slave modes. They can support standard and fast modes.

They support dual slave addressing (7-bit only) and both 7/10-bit addressing in master mode. A hardware CRC generation/verification is embedded.

They can be served by DMA and they support SM Bus 2.0/PM Bus.

2.3.17 Universal synchronous/asynchronous receiver transmitter (USART)

One of the USART interfaces is able to communicate at speeds of up to 4.5 Mbit/s. The other available interfaces communicate at up to 2.25 Mbit/s. They provide hardware management of the CTS and RTS signals, IrDA SIR ENDEC support, are ISO 7816 compliant and have LIN Master/Slave capability.

All USART interfaces can be served by the DMA controller.

2.3.18 Serial peripheral interface (SPI)

Up to two SPIs are able to communicate up to 18 Mbits/s in slave and master modes in fullduplex and simplex communication modes. The 3-bit prescaler gives 8 master mode frequencies and the frame is configurable to 8 bits or 16 bits. The hardware CRC generation/verification supports basic SD Card/MMC modes.

Both SPIs can be served by the DMA controller.

2.3.19 Controller area network (CAN)

The CAN is compliant with specifications 2.0A and B (active) with a bit rate up to 1 Mbit/s. It can receive and transmit standard frames with 11-bit identifiers as well as extended frames with 29-bit identifiers. It has three transmit mailboxes, two receive FIFOs with 3 stages and 14 scalable filter banks.

2.3.20 Universal serial bus (USB)

The STM32F103xx performance line embeds a USB device peripheral compatible with the USB full-speed 12 Mbs. The USB interface implements a full-speed (12 Mbit/s) function interface. It has software-configurable endpoint setting and suspend/resume support. The dedicated 48 MHz clock is generated from the internal main PLL (the clock source must use a HSE crystal oscillator).



2.3.21 GPIOs (general-purpose inputs/outputs)

Each of the GPIO pins can be configured by software as output (push-pull or open-drain), as input (with or without pull-up or pull-down) or as peripheral alternate function. Most of the GPIO pins are shared with digital or analog alternate functions. All GPIOs are high-current-capable except for analog inputs.

The I/Os alternate function configuration can be locked if needed following a specific sequence in order to avoid spurious writing to the I/Os registers.

I/Os on APB2 with up to 18 MHz toggling speed

2.3.22 ADC (analog-to-digital converter)

Two 12-bit analog-to-digital converters are embedded into STM32F103xx performance line devices and each ADC shares up to 16 external channels, performing conversions in single-shot or scan modes. In scan mode, automatic conversion is performed on a selected group of analog inputs.

Additional logic functions embedded in the ADC interface allow:

- Simultaneous sample and hold
- Interleaved sample and hold
- Single shunt

The ADC can be served by the DMA controller.

An analog watchdog feature allows very precise monitoring of the converted voltage of one, some or all selected channels. An interrupt is generated when the converted voltage is outside the programmed thresholds.

The events generated by the general-purpose timers (TIMx) and the advanced-control timer (TIM1) can be internally connected to the ADC start trigger, injection trigger, and DMA trigger respectively, to allow the application to synchronize A/D conversion and timers.

2.3.23 Temperature sensor

The temperature sensor has to generate a voltage that varies linearly with temperature. The conversion range is between 2 V < V_{DDA} < 3.6 V. The temperature sensor is internally connected to the ADC12_IN16 input channel which is used to convert the sensor output voltage into a digital value.

2.3.24 Serial wire JTAG debug port (SWJ-DP)

The ARM SWJ-DP Interface is embedded. and is a combined JTAG and serial wire debug port that enables either a serial wire debug or a JTAG probe to be connected to the target. The JTAG TMS and TCK pins are shared with SWDIO and SWCLK, respectively, and a specific sequence on the TMS pin is used to switch between JTAG-DP and SW-DP.





Figure 5. STM32F103xx performance line LQFP64 pinout



	1	2	3	4	5	6	7	8
A	• /PC14-, 0\\$C32_lN	, PC13-; FAMPER-RT	(PB9)	(PB4)	(PB3)	(PA15)	(PA14)	(PA13)
В	, PC15-, OS(C32_OUT	VBAT	(PB8)	BOOTO	(PD2)	(PC11)	(PC10)	(PA12)
С	OSC_IN	VSS_4	(PB7)	(PB5)	(PC12)	(PA10)	(PA9)	(PA11)
D	OSC_OUT	VDD_4	(PB6)	'VSS_3'	VSS_2	,VSS_1,	(PA8)	(PC9)
E	(NRST)	(PC1)	(PC0)	'V _{DD_3} '	'V _{DD_2} '	, VDD_1,	(PC7)	(PC8)
F	(V _{SSA})	(PC2)	(PA2)	(PA5)	(PB0)	(PC6)	(PB15)	(PB14)
G	WREF+	PÁO-WKŲP	(PA3)	(PA6)	(PB1)	(PB2)	(PB10)	(PB13)
н	VDDA,	(PA1)	(PA4)	(PA7)	(PC4)	(PC5)	(PB11)	(PB12)
								Al1549

Figure 6. STM32F103xx performance line TFBGA64 ballout



		Pir	IS					(2)		Alternate functions	
LFBGA100	LQFP48	TFBGA64	LQFP64	LQFP100	VFQFPN36	Pin name	Type ⁽¹⁾	I / O Level	Main function ⁽³⁾ (after reset)	Default	Remap
К2	13	G3	17	26	10	PA3	I/O		PA3	USART2_RX ⁽⁷⁾ / ADC12_IN3/ TIM2_CH4 ⁽⁷⁾	
E4	-	C2	18	27	-	V_{SS_4}	S		V _{SS_4}		
F4	-	D2	19	28	-	V_{DD_4}	S		V _{DD_4}		
G3	14	HЗ	20	29	11	PA4	I/O		PA4	SPI1_NSS ⁽⁷⁾ / USART2_CK ⁽⁷⁾ / ADC12_IN4	
НЗ	15	F4	21	30	12	PA5	I/O		PA5	SPI1_SCK ⁽⁷⁾ / ADC12_IN5	
JЗ	16	G4	22	31	13	PA6	I/O		PA6	SPI1_MISO ⁽⁷⁾ / ADC12_IN6/ TIM3_CH1 ⁽⁷⁾	TIM1_BKIN
КЗ	17	H4	23	32	14	PA7	I/O		PA7	SPI1_MOSI ⁽⁷⁾ / ADC12_IN7/ TIM3_CH2 ⁽⁷⁾	TIM1_CH1N
G4	-	H5	24	33		PC4	I/O		PC4	ADC12_IN14	
H4	-	H6	25	34		PC5	I/O		PC5	ADC12_IN15	
J4	18	F5	26	35	15	PB0	I/O		PB0	ADC12_IN8/ TIM3_CH3 ⁽⁷⁾	TIM1_CH2N
K4	19	G5	27	36	16	PB1	I/O		PB1	ADC12_IN9/ TIM3_CH4 ⁽⁷⁾	TIM1_CH3N
G5	20	G6	28	37	17	PB2	I/O	FT	PB2/BOOT1		
H5	-	-	-	38	-	PE7	I/O	FT	PE7		TIM1_ETR
J5	-	•	-	39	-	PE8	I/O	FT	PE8		TIM1_CH1N
K5	-	-	-	40	-	PE9	I/O	FT	PE9		TIM1_CH1
G6	-	-	-	41	-	PE10	I/O	FT	PE10		TIM1_CH2N
H6	-	-	-	42	-	PE11	I/O	FT	PE11		TIM1_CH2
J6	-	-	-	43	-	PE12	I/O	FT	PE12		TIM1_CH3N
K6	-	-	-	44	-	PE13	I/O	FT	PE13		TIM1_CH3
G7	-	-	-	45	-	PE14	I/O	FT	PE14		TIM1_CH4
H7	-	-	-	46	-	PE15	I/O	FT	PE15		TIM1_BKIN
J7	21	G7	29	47	-	PB10	I/O	FT	PB10	I2C2_SCL/ USART3_TX ⁽⁷⁾	TIM2_CH3
K7	22	H7	30	48	-	PB11	I/O	FT	PB11	I2C2_SDA/ USART3_RX ⁽⁷⁾	TIM2_CH4
E7	23	D6	31	49	18	V _{SS_1}	S		V _{SS_1}		

Table 5. Medium-density STM32F103xx pin definit	ions (continued)
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		Pin	IS					(2)		Alternate functions	
LFBGA100	LQFP48	TFBGA64	LQFP64	LQFP100	VFQFPN36	Pin name	Type ⁽¹⁾	I / O Level	Main function ⁽³⁾ (after reset)	Default	Remap
F7	24	E6	32	50	19	V _{DD_1}	S		V_{DD_1}		
K8	25	H8	33	51	-	PB12	I/O	FT	PB12	SPI2_NSS/ I2C2_SMBAI/ USART3_CK ⁽⁷⁾ / TIM1_BKIN ⁽⁷⁾	
J8	26	G8	34	52	-	PB13	I/O	FT	PB13	SPI2_SCK/ USART3_CTS ⁽⁷⁾ / TIM1_CH1N ⁽⁷⁾	
H8	27	F8	35	53	-	PB14	I/O	FT	PB14	SPI2_MISO/ USART3_RTS ⁽⁷⁾ TIM1_CH2N ⁽⁷⁾	
G8	28	F7	36	54	-	PB15	I/O	FT	PB15	SPI2_MOSI/ TIM1_CH3N ⁽⁷⁾	
K9	-	-	-	55	-	PD8	I/O	FT	PD8		USART3_TX
J9	-	-	-	56	-	PD9	I/O	FT	PD9		USART3_RX
H9	-	I	•	57	-	PD10	I/O	FT	PD10		USART3_CK
G9	-	•	-	58	-	PD11	I/O	FT	PD11		USART3_CTS
K10	-	-	-	59	-	PD12	I/O	FT	PD12		TIM4_CH1 / USART3_RTS
J10	-	-	-	60	-	PD13	I/O	FT	PD13		TIM4_CH2
H10	-	I	•	61	-	PD14	I/O	FT	PD14		TIM4_CH3
G10	-	-	-	62	-	PD15	I/O	FT	PD15		TIM4_CH4
F10	-	F6	37	63	-	PC6	I/O	FT	PC6		TIM3_CH1
E10		E7	38	64	-	PC7	I/O	FT	PC7		TIM3_CH2
F9		E8	39	65	-	PC8	I/O	FT	PC8		TIM3_CH3
E9	-	D8	40	66	-	PC9	I/O	FT	PC9		TIM3_CH4
D9	29	D7	41	67	20	PA8	I/O	FT	PA8	USART1_CK/ TIM1_CH1 ⁽⁷⁾ /MCO	
C9	30	C7	42	68	21	PA9	I/O	FT	PA9	USART1_TX ⁽⁷⁾ / TIM1_CH2 ⁽⁷⁾	
D10	31	C6	43	69	22	PA10	I/O	FT	PA10	USART1_RX ⁽⁷⁾ / TIM1_CH3 ⁽⁷⁾	
C10	32	C8	44	70	23	PA11	I/O	FT	PA11	USART1_CTS/ CANRX ⁽⁷⁾ / USBDM TIM1_CH4 ⁽⁷⁾	
B10	33	B8	45	71	24	PA12	I/O	FT	PA12	USART1_RTS/ CANTX ⁽⁷⁾ //USBDP TIM1_ETR ⁽⁷⁾	

Table 5. Medium-density STM32F103xx pin definitions (continued)



Pins								(2)		Alternate f	unctions
LFBGA100	LQFP48	TFBGA64	LQFP64	LQFP100	VFQFPN36	Pin name	Type ⁽¹⁾	I / O Leve	Main function ⁽³⁾ (after reset)	Default	Remap
D4	-	-	-	97	-	PE0	I/O	FT	PE0	TIM4_ETR	
C4	-	-	-	98	-	PE1	I/O	FT	PE1		
E5	47	D4	63	99	36	V _{SS_3}	S		V _{SS_3}		
F5	48	E4	64	100	1	V _{DD_3}	S		V _{DD_3}		

 Table 5.
 Medium-density STM32F103xx pin definitions (continued)

1. I = input, O = output, S = supply, HiZ = high impedance.

2. FT = 5 V tolerant.

- 3. Function availability depends on the chosen device. For devices having reduced peripheral counts, it is always the lower number of peripheral that is included. For example, if a device has only one SPI and two USARTs, they will be called SPI1 and USART1 & USART2, respectively. Refer to *Table 2 on page 10*.
- 4. PC13, PC14 and PC15 are supplied through the power switch and since the switch only sinks a limited amount of current (3 mA), the use of GPIOs PC13 to PC15 is restricted: only one I/O at a time can be used as an output, the speed has to be limited to 2 MHz with a maximum load of 30 pF and these I/Os must not be used as a current source (e.g. to drive an LED).
- 5. Main function after the first backup domain power-up. Later on, it depends on the contents of the Backup registers even after reset (because these registers are not reset by the main reset). For details on how to manage these IOs, refer to the Battery backup domain and BKP register description sections in the STM32F10xxx reference manual, available from the STMicroelectronics website: www.st.com.
- 6. Unlike in the LQFP64 package, there is no PC3 in the TFBGA64 package. The V_{REF+} functionality is provided instead.
- This alternate function can be remapped by software to some other port pins (if available on the used package). For more
 details, refer to the Alternate function I/O and debug configuration section in the STM32F10xxx reference manual, available
 from the STMicroelectronics website: www.st.com.
- 8. The pins number 2 and 3 in the VFQFPN36 package, 5 and 6 in the LQFP48 and LQFP64 packages, and C1 and C2 in the TFBGA64 package are configured as OSC_IN/OSC_OUT after reset, however the functionality of PD0 and PD1 can be remapped by software on these pins. For the LQFP100 package, PD0 and PD1 are available by default, so there is no need for remapping. For more details, refer to the Alternate function I/O and debug configuration section in the STM32F10xxx reference manual.

The use of PD0 and PD1 in output mode is limited as they can only be used at 50 MHz in output mode.





Symbol	Devemeter	Conditions		Ma	Unit	
Symbol	Parameter	Conditions	HCLK	T _A = 85 °C	T _A = 105 °C	onic
			72 MHz	50	50.3	
			48 MHz	36.1	36.2	
		External clock ⁽²⁾ , all	36 MHz	28.6	28.7	
	Supply current in	peripherals enabled	24 MHz	19.9	20.1	
			16 MHz	14.7	14.9	
			8 MHz	8.6	8.9	m۸
'DD	Run mode		72 MHz	32.8	32.9	
			48 MHz	24.4	24.5	
		External clock ⁽²⁾ , all	36 MHz	19.8	19.9	
		peripherals disabled	24 MHz	13.9	14.2	-
			16 MHz	10.7	11	
			8 MHz	6.8	7.1	1

Table 13.Maximum current consumption in Run mode, code with data processing
running from Flash

1. Based on characterization, not tested in production.

2. External clock is 8 MHz and PLL is on when f_{HCLK} > 8 MHz.

Table 14.Maximum current consumption in Run mode, code with data processing
running from RAM

Symbol	Parameter	Conditions	f	Ма	Unit	
Symbol	Farailleter	Conumons	HCLK	T _A = 85 °C	T _A = 105 °C	Onit
			72 MHz	48	50	
			48 MHz	31.5	32	
		External clock ⁽²⁾ , all	36 MHz	24	25.5	
		peripherals enabled	24 MHz	17.5	18	
			16 MHz	12.5	13	m۸
I	Supply		8 MHz	7.5	8	
'DD	Run mode		72 MHz	29	29.5	
			48 MHz	20.5	21	-
		External clock ⁽²⁾ , all	36 MHz	16	16.5	
		peripherals disabled	24 MHz	11.5	12	
			16 MHz	8.5	9	
			8 MHz	5.5	6	

1. Based on characterization, tested in production at V_{DD} max, f_{HCLK} max.

2. External clock is 8 MHz and PLL is on when f_{HCLK} > 8 MHz.



On-chip peripheral current consumption

The current consumption of the on-chip peripherals is given in *Table 19*. The MCU is placed under the following conditions:

- all I/O pins are in input mode with a static value at V_{DD} or V_{SS} (no load)
- all peripherals are disabled unless otherwise mentioned
- the given value is calculated by measuring the current consumption
 - with all peripherals clocked off
 - with only one peripheral clocked on
- ambient operating temperature and V_{DD} supply voltage conditions summarized in Table 6

Pe	ripheral	Typical consumption at 25 °C	Unit	
	TIM2	1.2		
	TIM3	1.2		
	TIM4	0.9		
	SPI2	0.2		
	USART2	0.35	m (
AFDI	USART3	0.35	ША	
	I2C1	0.39		
	I2C2	0.39		
	USB	0.65		
	CAN	0.72		
	GPIO A	0.47		
	GPIO B	0.47		
	GPIO C	0.47		
	GPIO D	0.47		
	GPIO E	0.47	m۸	
AFDZ	ADC1 ⁽²⁾	1.81	ША	
	ADC2	1.78		
	TIM1	1.6		
	SPI1	0.43		
	USART1	0.85		

 Table 19.
 Peripheral current consumption⁽¹⁾

1. $f_{HCLK} = 72 \text{ MHz}, f_{APB1} = f_{HCLK}/2, f_{APB2} = f_{HCLK}$, default prescaler value for each peripheral.

 Specific conditions for ADC: f_{HCLK} = 56 MHz, f_{APB1} = f_{HCLK}/2, f_{APB2} = f_{HCLK}, f_{ADCCLK} = f_{APB2/4}, ADON bit in the ADC_CR2 register is set to 1.



Symbol	Parameter	Conditions	Min	Тур	Max	Unit
f _{OSC_IN}	Oscillator frequency		4	8	16	MHz
R _F	Feedback resistor			200		kΩ
$C_{L1} \\ C_{L2}^{(3)}$	Recommended load capacitance versus equivalent serial resistance of the crystal $(R_S)^{(4)}$	R _S = 30 Ω		30		pF
i ₂	HSE driving current	V_{DD} = 3.3 V, V_{IN} = V_{SS} with 30 pF load			1	mA
9 _m	Oscillator transconductance	Startup	25			mA/V
t _{SU(HSE} ⁽⁵⁾	startup time	V _{DD} is stabilized		2		ms

 Table 22.
 HSE 4-16 MHz oscillator characteristics^{(1) (2)}

1. Resonator characteristics given by the crystal/ceramic resonator manufacturer.

2. Based on characterization, not tested in production.

- 3. For C_{L1} and C_{L2} it is recommended to use high-quality ceramic capacitors in the 5 pF to 25 pF range (typ.), designed for high-frequency applications, and selected to match the requirements of the crystal or resonator. C_{L1} and C_{L2} are usually the same size. The crystal manufacturer typically specifies a load capacitance which is the series combination of C_{L1} and C_{L2} . PCB and MCU pin capacitance must be included (10 pF can be used as a rough estimate of the combined pin and board capacitance) when sizing C_{L1} and C_{L2} .
- 4. The relatively low value of the RF resistor offers a good protection against issues resulting from use in a humid environment, due to the induced leakage and the bias condition change. However, it is recommended to take this point into account if the MCU is used in tough humidity conditions.
- t_{SU(HSE)} is the startup time measured from the moment it is enabled (by software) to a stabilized 8 MHz oscillation is reached. This value is measured for a standard crystal resonator and it can vary significantly with the crystal manufacturer



Figure 21. Typical application with an 8 MHz crystal

1. R_{EXT} value depends on the crystal characteristics. Typical value is in the range of 5 to 6R_S.

Low-speed external clock generated from a crystal/ceramic resonator

The low-speed external (LSE) clock can be supplied with a 32.768 kHz crystal/ceramic resonator oscillator. All the information given in this paragraph are based on characterization results obtained with typical external components specified in *Table 23*. In the application, the resonator and the load capacitors have to be placed as close as possible to the oscillator pins in order to minimize output distortion and startup stabilization time. Refer to the crystal resonator manufacturer for more details on the resonator characteristics (frequency, package, accuracy).



Equation 1: R_{AIN} max formula:

$$R_{AIN} < \frac{I_{S}}{f_{ADC} \times C_{ADC} \times ln(2^{N+2})} - R_{ADC}$$

The formula above (*Equation 1*) is used to determine the maximum external impedance allowed for an error below 1/4 of LSB. Here N = 12 (from 12-bit resolution).

Table 46. R_{AIN} max for $f_{ADC} = 14 \text{ MHz}^{(1)}$

T _s (cycles)	t _S (μs)	R _{AIN} max (kΩ)
1.5	0.11	1.2
7.5	0.54	10
13.5	0.96	19
28.5	2.04	41
41.5	2.96	60
55.5	3.96	80
71.5	5.11	104
239.5	17.1	350

1. Based on characterization, not tested in production.

Table 47. ADC accuracy - limited test conditions^{(1) (2)}

Symbol	Parameter	Test conditions	Тур	Max ⁽³⁾	Unit
ET	Total unadjusted error	f _{PCLK2} = 56 MHz,	±1.3	±2	
EO	Offset error	$f_{ADC} = 14 \text{ MHz}, \text{R}_{AIN} < 10 \text{k}\Omega,$	±1	±1.5	
EG	Gain error	$V_{DDA} = 3 V \text{ to } 3.6 V$ T _A = 25 °C	±0.5	±1.5	LSB
ED	Differential linearity error	Measurements made after	±0.7	±1	
EL	Integral linearity error	ADC calibration	±0.8	±1.5	

1. ADC DC accuracy values are measured after internal calibration.

 ADC Accuracy vs. Negative Injection Current: Injecting negative current on any of the standard (non-robust) analog input pins should be avoided as this significantly reduces the accuracy of the conversion being performed on another analog input. It is recommended to add a Schottky diode (pin to ground) to standard analog pins which may potentially inject negative current. Any positive injection current within the limits specified for I_{INJ(PIN)} and ΣI_{INJ(PIN)} in *Section 5.3.12* does not affect the ADC accuracy.

3. Based on characterization, not tested in production.





Figure 31. Typical connection diagram using the ADC

1. Refer to Table 45 for the values of R_{AIN} , R_{ADC} and C_{ADC} .

 C_{parasitic} represents the capacitance of the PCB (dependent on soldering and PCB layout quality) plus the pad capacitance (roughly 7 pF). A high C_{parasitic} value will downgrade conversion accuracy. To remedy this, f_{ADC} should be reduced.

General PCB design guidelines

Power supply decoupling should be performed as shown in *Figure 32* or *Figure 33*, depending on whether $V_{\text{REF+}}$ is connected to V_{DDA} or not. The 10 nF capacitors should be ceramic (good quality). They should be placed them as close as possible to the chip.





1. V_{REF+} and V_{REF-} inputs are available only on 100-pin packages.





1. Drawing is not to scale.

2. The back-side pad is not internally connected to the V_{SS} or V_{DD} power pads.

3. There is an exposed die pad on the underside of the VFQFPN package. It should be soldered to the PCB. All leads should also be soldered to the PCB.

Symbol	millimeters			inches ⁽¹⁾			
Symbol	Min	Тур	Max	Min	Тур	Max	
A	0.800	0.900	1.000	0.0315	0.0354	0.0394	
A1		0.020	0.050		0.0008	0.0020	
A2		0.650	1.000		0.0256	0.0394	
A3		0.250			0.0098		
b	0.180	0.230	0.300	0.0071	0.0091	0.0118	
D	5.875	6.000	6.125	0.2313	0.2362	0.2411	
D2	1.750	3.700	4.250	0.0689	0.1457	0.1673	
E	5.875	6.000	6.125	0.2313	0.2362	0.2411	
E2	1.750	3.700	4.250	0.0689	0.1457	0.1673	
е	0.450	0.500	0.550	0.0177	0.0197	0.0217	
L	0.350	0.550	0.750	0.0138	0.0217	0.0295	
ddd		0.080			0.0031		

Table 50. VFQFPN36 6 x 6 mm, 0.5 mm pitch, package mechanical data

1. Values in inches are converted from mm and rounded to 4 decimal digits.



Figure 35. Recommended footprint (dimensions in mm)⁽¹⁾⁽²⁾⁽³⁾







Figure 44. LQFP48, 48-pin low-profile quad flat package outline⁽¹⁾





1. Drawing is not to scale.

2. Dimensions are in millimeters.

Table 55.	LQFP48, 48-pin	low-profile q	uad flat packa	ge mechanical data
				J

Symbol	millimeters			inches ⁽¹⁾		
Symbol	Тур	Min	Мах	Тур	Min	Мах
A			1.600			0.0630
A1		0.050	0.150		0.0020	0.0059
A2	1.400	1.350	1.450	0.0551	0.0531	0.0571
b	0.220	0.170	0.270	0.0087	0.0067	0.0106
с		0.090	0.200		0.0035	0.0079
D	9.000	8.800	9.200	0.3543	0.3465	0.3622
D1	7.000	6.800	7.200	0.2756	0.2677	0.2835
D3	5.500			0.2165		
E	9.000	8.800	9.200	0.3543	0.3465	0.3622
E1	7.000	6.800	7.200	0.2756	0.2677	0.2835
E3	5.500			0.2165		
е	0.500			0.0197		
L	0.600	0.450	0.750	0.0236	0.0177	0.0295
L1	1.000			0.0394		
k	3.5°	0°	7 °	3.5°	0°	7 °
CCC		0.080	•		0.0031	

1. Values in inches are converted from mm and rounded to 4 decimal digits.



6.2 Thermal characteristics

The maximum chip junction temperature (T_Jmax) must never exceed the values given in *Table 9: General operating conditions on page 35*.

The maximum chip-junction temperature, $T_{\rm J}$ max, in degrees Celsius, may be calculated using the following equation:

$$T_J max = T_A max + (P_D max \times \Theta_{JA})$$

Where:

- T_A max is the maximum ambient temperature in °C,
- Θ_{JA} is the package junction-to-ambient thermal resistance, in °C/W,
- P_D max is the sum of P_{INT} max and P_{I/O} max (P_D max = P_{INT} max + P_{I/O}max),
- P_{INT} max is the product of I_{DD} and V_{DD}, expressed in Watts. This is the maximum chip internal power.

 $P_{I/O}$ max represents the maximum power dissipation on output pins where:

 $\mathsf{P}_{\mathsf{I}/\mathsf{O}} \max = \Sigma \; (\mathsf{V}_{\mathsf{OL}} \times \mathsf{I}_{\mathsf{OL}}) + \Sigma ((\mathsf{V}_{\mathsf{DD}} - \mathsf{V}_{\mathsf{OH}}) \times \mathsf{I}_{\mathsf{OH}}),$

taking into account the actual V_{OL} / I_{OL} and V_{OH} / I_{OH} of the I/Os at low and high level in the application.

Table 56. Package thermal characteristics

Symbol	Parameter	Value	Unit
Θ_{JA}	Thermal resistance junction-ambient LFBGA100 - 10 × 10 mm / 0.8 mm pitch	44	
	Thermal resistance junction-ambient LQFP100 - 14 × 14 mm / 0.5 mm pitch	46	
	Thermal resistance junction-ambient LQFP64 - 10 × 10 mm / 0.5 mm pitch	45	°C/M
	Thermal resistance junction-ambient TFBGA64 - 5 × 5 mm / 0.5 mm pitch	65	0/11
	Thermal resistance junction-ambient LQFP48 - 7 x 7 mm / 0.5 mm pitch	55	
	Thermal resistance junction-ambient VFQFPN 36 - 6 × 6 mm / 0.5 mm pitch	18	

6.2.1 Reference document

JESD51-2 Integrated Circuits Thermal Test Method Environment Conditions - Natural Convection (Still Air). Available from www.jedec.org.



6.2.2 Selecting the product temperature range

When ordering the microcontroller, the temperature range is specified in the ordering information scheme shown in *Table 57: Ordering information scheme*.

Each temperature range suffix corresponds to a specific guaranteed ambient temperature at maximum dissipation and, to a specific maximum junction temperature.

As applications do not commonly use the STM32F103xx at maximum dissipation, it is useful to calculate the exact power consumption and junction temperature to determine which temperature range will be best suited to the application.

The following examples show how to calculate the temperature range needed for a given application.

Example 1: High-performance application

Assuming the following application conditions:

Maximum ambient temperature $T_{Amax} = 82$ °C (measured according to JESD51-2), $I_{DDmax} = 50$ mA, $V_{DD} = 3.5$ V, maximum 20 I/Os used at the same time in output at low level with $I_{OL} = 8$ mA, $V_{OL} = 0.4$ V and maximum 8 I/Os used at the same time in output at low level with $I_{OL} = 20$ mA, $V_{OL} = 1.3$ V

 $P_{INTmax} = 50 \text{ mA} \times 3.5 \text{ V} = 175 \text{ mW}$

 $P_{IOmax} = 20 \times 8 \text{ mA} \times 0.4 \text{ V} + 8 \times 20 \text{ mA} \times 1.3 \text{ V} = 272 \text{ mW}$

This gives: $P_{INTmax} = 175 \text{ mW}$ and $P_{IOmax} = 272 \text{ mW}$:

 $P_{Dmax} = 175 + 272 = 447 \text{ mW}$

Thus: $P_{Dmax} = 447 \text{ mW}$

Using the values obtained in *Table 56* T_{Jmax} is calculated as follows:

- For LQFP100, 46 °C/W

T_{Jmax} = 82 °C + (46 °C/W × 447 mW) = 82 °C + 20.6 °C = 102.6 °C

This is within the range of the suffix 6 version parts ($-40 < T_J < 105 \text{ °C}$).

In this case, parts must be ordered at least with the temperature range suffix 6 (see *Table 57: Ordering information scheme*).

Example 2: High-temperature application

Using the same rules, it is possible to address applications that run at high ambient temperatures with a low dissipation, as long as junction temperature T_J remains within the specified range.

Assuming the following application conditions:

Maximum ambient temperature $T_{Amax} = 115 \text{ °C}$ (measured according to JESD51-2), $I_{DDmax} = 20 \text{ mA}$, $V_{DD} = 3.5 \text{ V}$, maximum 20 I/Os used at the same time in output at low level with $I_{OL} = 8 \text{ mA}$, $V_{OL} = 0.4 \text{ V}$ $P_{INTmax} = 20 \text{ mA} \times 3.5 \text{ V} = 70 \text{ mW}$ $P_{IOmax} = 20 \times 8 \text{ mA} \times 0.4 \text{ V} = 64 \text{ mW}$ This gives: $P_{INTmax} = 70 \text{ mW}$ and $P_{IOmax} = 64 \text{ mW}$: $P_{Dmax} = 70 + 64 = 134 \text{ mW}$ Thus: $P_{Dmax} = 134 \text{ mW}$



Date	Revision	Changes
		 I/O information clarified on page 1. <i>Figure 3: STM32F103xx performance line LFBGA100 ballout</i> modified. <i>Figure 9: Memory map</i> modified. <i>Table 4: Timer feature comparison</i> added. PB4, PB13, PB14, PB15, PB3/TRACESWO moved from Default column to Remap column in <i>Table 5: Medium-density STM32F103xx pin definitions</i>.
23-Apr-2009	10	P _D for LFBGA100 corrected in <i>Table 9: General operating conditions</i> .
		Note modified in Table 13: Maximum current consumption in Run mode, code with data processing running from Flash and Table 15: Maximum current consumption in Sleep mode, code running from Flash or RAM.
		Table 20: High-speed external user clock characteristics and Table 21:Low-speed external user clock characteristics modified.
		<i>Figure 17</i> shows a typical curve (title modified). ACC _{HSI} max values modified in <i>Table 24: HSI oscillator characteristics</i> .
		TFBGA64 package added (see <i>Table 54</i> and <i>Table 42</i>). Small text changes.

Table 58. Document revision history (continued)

